



N-Channel Reduced Q_g, Fast Switching MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$V_{DS}(V)$ $R_{DS(on)}(\Omega)$				
12	0.0055 at V _{GS} = 4.5 V	17			
12	0.008 at V _{GS} = 2.5 V	14			

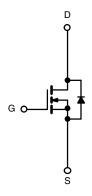
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFETs
- · PWM Optimized for High Efficiency
- Low Output Voltage
- 100 % R_q Tested

ROHS COMPLIANT HALOGEN FREE Available

APPLICATIONS

- Synchronous Rectifier
- · Point-of-Load Synchronous Buck Converter



N-Channel MOSFET

		SO-8		
s	1		8	D
S	2		7	D
S	3		6	D
G	4		5	D
		Ton View		

Ordering Information: Si4866DY-T1-E3 (Lead Pb)-free)

Si4866DY-T1-GE3 (Lead Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	$I_A = 25$ °C, unles	ss omerwise r	iotea		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	12		V
Gate-Source Voltage		V_{GS}	± 8		V
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	17	11	
	T _A = 70 °C		14	8	
Pulsed Drain Current		I _{DM}	± 50		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.7	1.40	
M · D D · · · · a	T _A = 25 °C	P _D	3.0	1.6	14/
Maximum Power Dissipation ^a	T _A = 70 °C	L D	2.0	1.0	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipular lunction to Ambient (MOCFET)	t ≤ 10 s	R_{thJA}	34	41	°C/W
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		67	80	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	15	19	

Notes

a. Surface Mounted on 1" x 1" FR4 board.

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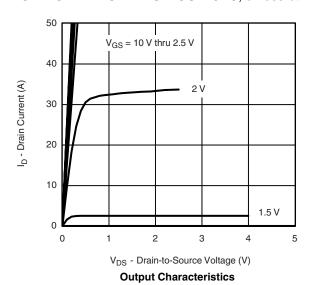
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	<u> </u>		•				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zava Cata Valtaga Drain Current	1	V _{DS} = 9.6 V, V _{GS} = 0 V	9.6 V, V _{GS} = 0 V		1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 9.6 V, V _{GS} = 0 V, T _J = 70 °C			5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	40			Α	
	_	V _{GS} = 4.5 V, I _D = 17		0.0045	0.0055		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 14$		0.0065	0.008	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 6 \text{ V}, I_{D} = 17$		80		S	
Diode Forward Voltage ^a	V _{SD}	$I_S = 2.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.70	1.1	٧	
Dynamic ^b			\!\	•	'		
Total Gate Charge	Qg			21	30		
Gate-Source Charge	Q_{gs}	$V_{DS} = 6 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 17 \text{ A}$		4.6		nC	
Gate-Drain Charge	Q_{gd}			3.5		1	
Gate Resistance	R_{G}		1.5	2.3	3.9	Ω	
Turn-On Delay Time	t _{d(on)}			28	42		
Rise Time	t _r	V_{DD} = 6 V, R_L = 6 Ω		32	48		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong\text{1 A, V}_\text{GEN}=\text{4.5 V, R}_\text{G}=\text{6}~\Omega$		82	123	ns	
Fall Time	t _f			35	53		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.7 A, dI/dt = 100 A/μs		60	90		

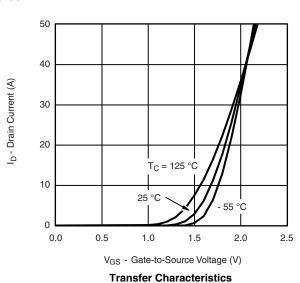
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

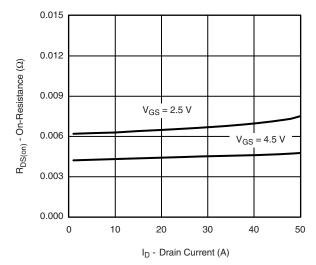




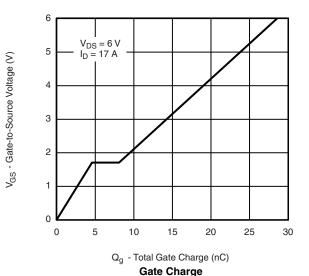




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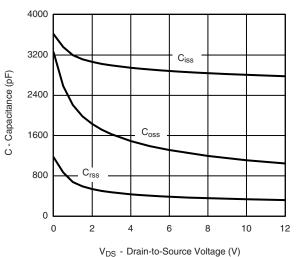


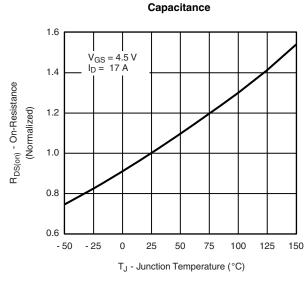
On-Resistance vs. Drain Current



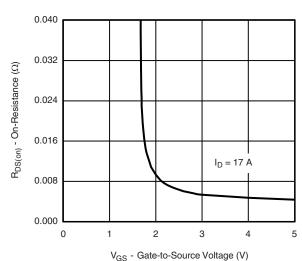
50 T_J = 150 °C 10 $T_J = 25$ °C 0.00 0.2 0.4 0.6 0.8 1.0 V_{SD} - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage





On-Resistance vs. Junction Temperature



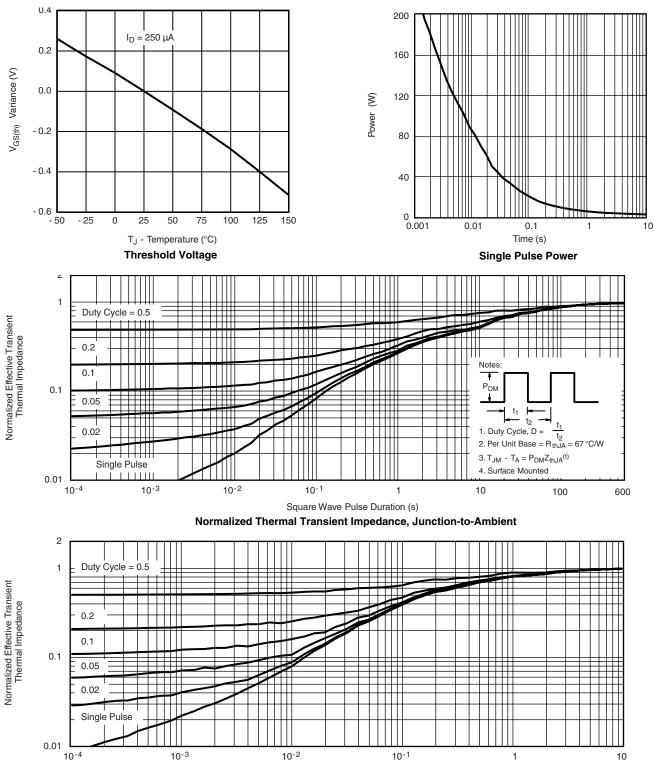
On-Resistance vs. Gate-to-Source Voltage

I_S - Source Current (A)

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



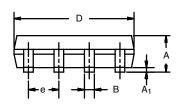
Square Wave Pulse Duration (s)
Normalized Thermal Transient Impedance, Junction-to-Foot

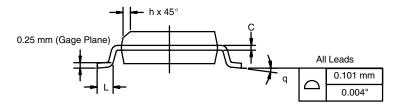
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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







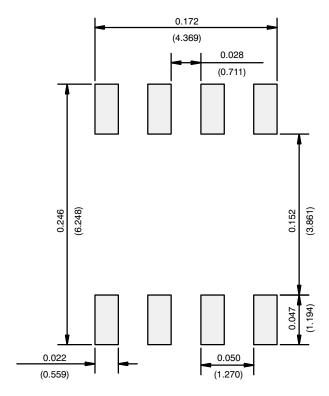
	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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